

ES1AW THRU ES1JW

SURFACE MOUNT SUPERFAST RECOVERY RECTIFIER



康比電子
HORNBY ELECTRONIC

REVERSE VOLTAGE: 50 to 600 VOLTS
FORWARD CURRENT: 1.0 AMPERE

FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-O
- For surface mounted applications
- Low profile package
- Easy pick and place
- Built-in strain relief
- Low forward voltage drop
- High temperature soldering : 250°C /10 seconds at terminals

MECHANICAL DATA

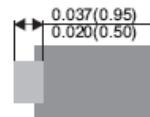
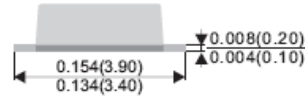
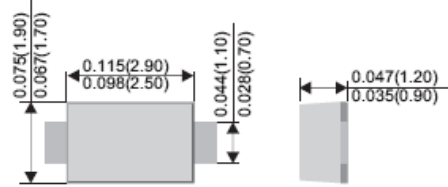
Case: Molded plastic, SOD-123FL

Terminals: Solder plated, solderable per MIL-STD-750, method 2026 guaranteed

Polarity: Color band denotes cathode end

Packaging: 12mm tape per EIA STD RS-481

SOD-123FL



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbols	ES1AW	ES1BW	ES1DW	ES1GW	ES1JW	Units
Marking Code		E1	E2	E3	E4	E5	
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	Volts
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	Volts
Maximum Average Forward Rectified Current See Fig.2	$I_{(AV)}$	1.0					Amp
Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	30					Amp
Maximum Forward Voltage at 1.0A	V_F	0.95		1.25	1.70		Volts
Maximum Reverse Current at $T_A=25^\circ\text{C}$ at Rated DC Blocking Voltage $T_A=100^\circ\text{C}$	I_R	5.0 100					μAmp
Typical Junction Capacitance (Note 1)	C_J	15					pF
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	35					$^\circ\text{C/W}$
Maximum Reverse Recovery Time (Note 3)	T_{RR}	35					nS
Operating Junction Temperature Range	T_J	-55 to +150					$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150					$^\circ\text{C}$

NOTES:

1- Measured at 1 MHz and applied reverse voltage of 4.0 VDC.

2- P.C.B. mounted with 5.0 x 5.0mm copper pad areas.

3- Reverse Recovery Test Conditions: $I_F=5A$, $I_R=1A$, $I_{RR}=25A$.

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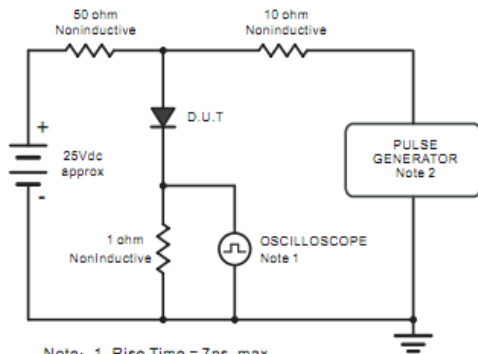
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RATINGS AND CHARACTERISTIC CURVES

Fig.1 Reverse Recovery Time Characteristic And Test Circuit Diagram



Note: 1. Rise Time = 7ns, max.
Input Impedance = 1 megohm, 22pF.
2. Rise Time = 10ns, max.
Source Impedance = 50 ohms.

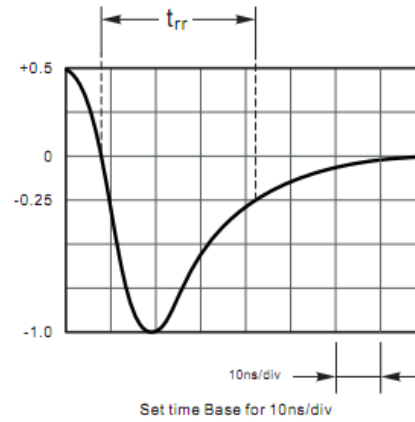


Fig.2 Maximum Average Forward Current Rating

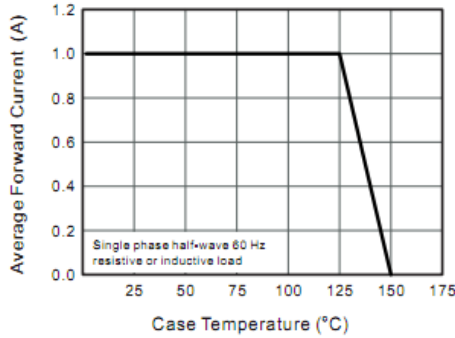


Fig.3 Typical Reverse Characteristics

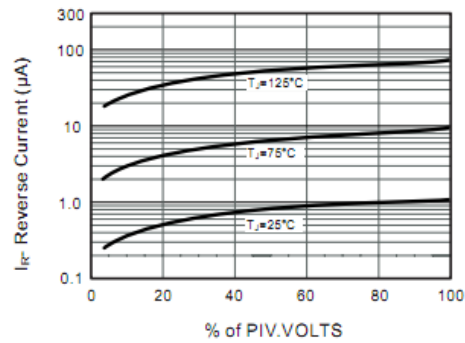


Fig.4 Typical Forward Characteristics

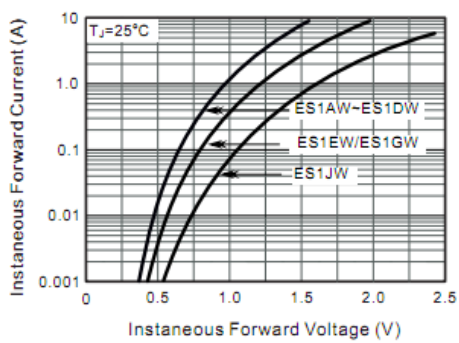


Fig.5 Typical Junction Capacitance

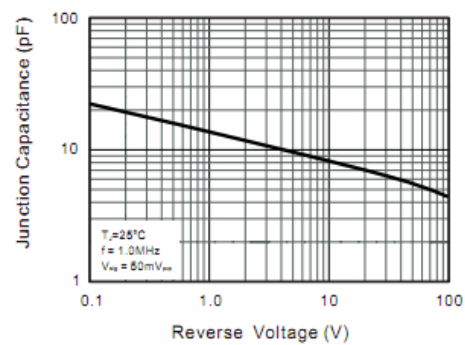


Fig.6 Maximum Non-Repetitive Peak Forward Surge Current

